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HALOGEN

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## Vishay Semiconductors

# **High Performance Schottky Rectifier, 3 A**

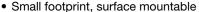


**SMA (DO-214AC)** 

| PRIMARY CHARACTERISTICS          |                 |  |  |  |
|----------------------------------|-----------------|--|--|--|
| I <sub>F(AV)</sub>               | 3 A             |  |  |  |
| $V_{R}$                          | 40 V            |  |  |  |
| V <sub>F</sub> at I <sub>F</sub> | 0.46 V          |  |  |  |
| I <sub>RM</sub>                  | 20 mA at 125 °C |  |  |  |
| T <sub>J</sub> max.              | 150 °C          |  |  |  |
| E <sub>AS</sub>                  | 6.0 mJ          |  |  |  |
| Package                          | SMA (DO-214AC)  |  |  |  |
| Circuit configuration            | Single          |  |  |  |

#### **FEATURES**

- Low forward voltage drop
- Guard ring for enhanced ruggedness and long term reliability



- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Meets JESD 201 class 2 whisker test
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **APPLICATIONS**

- Switching power supplies
- Meter protection
- Reverse protection for power input to PC board circuits
- · Battery isolation and charging
- Low threshold voltage diode
- Freewheeling or by-pass diode
- · Low voltage clamp

#### **DESCRIPTION**

The VS-30MQ040HM3 Schottky rectifier is designed to be used for low power applications where a reverse voltage of 40 V is encountered and surface mountable is required.

| MAJOR RATINGS AND CHARACTERISTICS |   |             |       |  |  |
|-----------------------------------|---|-------------|-------|--|--|
| SYMBOL                            | CHARACTERISTICS                             | VALUES      | UNITS |  |  |
| I <sub>F(AV)</sub>                | Rectangular waveform                        | 3           | Α     |  |  |
| V <sub>RRM</sub>                  |   | 40          | V     |  |  |
| I <sub>FSM</sub>                  | t <sub>p</sub> = 5 μs sine                  | 330         | Α     |  |  |
| V <sub>F</sub>                    | 2 A <sub>pk</sub> , T <sub>J</sub> = 125 °C | 0.43        | V     |  |  |
| TJ                                | Range                                       | -40 to +150 | °C    |  |  |

| VOLTAGE RATINGS                      |           |               |       |  |
|--------------------------------------|-----------|---------------|-------|--|
| PARAMETER                            | SYMBOL    | VS-30MQ040HM3 | UNITS |  |
| Maximum DC reverse voltage           | $V_R$     | 40            | V     |  |
| Maximum working peak reverse voltage | $V_{RWM}$ | 40            | V     |  |

| ABSOLUTE MAXIMUM RATINGS                      |  |   |  |        |       |
|---|--|---|--|--------|-------|
| PARAMETER                                     | SYMBOL   | TEST CONDITIONS   |  | VALUES | UNITS |
| Maximum average forward current<br>See fig. 4 | $I_{F(AV)}$ 50 % duty cycle at $T_L = 89$ °C, rectangular waveform On PC board 9 mm <sup>2</sup> island (0.013 mm thick copper pad area) |   | 3  | Α      |       |
| Maximum peak one cycle                        |  | 5 μs sine or 3 μs rect. pulse   | Following any rated                                    | 330    |       |
| non-repetitive surge current<br>See fig. 6    | I <sub>FSM</sub>   | 10 ms sine or 6 ms rect. pulse  | load condition and with rated V <sub>RRM</sub> applied | 140    | Α     |
| Non-repetitive avalanche energy               | E <sub>AS</sub>  | $T_J = 25 ^{\circ}\text{C}$ , $I_{AS} = 1 \text{A}$ , $L = 12 \text{mH}$  |  | 6.0    | mJ    |
| Repetitive avalanche current                  | I <sub>AR</sub>  | Current decaying linearly to zero in 1 $\mu$ s<br>Frequency limited by $T_J$ maximum $V_A = 1.5 \text{ x } V_R$ typical |  | 1.0    | Α     |



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| ELECTRICAL SPECIFICATIONS       |                                |   |                                       |        |       |
|---------------------------------|--------------------------------|---|---------------------------------------|--------|-------|
| PARAMETER                       | SYMBOL                         | TEST CONDITIONS   |                                       | VALUES | UNITS |
|                                 | V <sub>FM</sub> <sup>(1)</sup> | 1 A   | T <sub>J</sub> = 25 °C                | 0.42   | V     |
| Maximum forward voltage drop    |                                | 3 A   |                                       | 0.51   |       |
| See fig. 1                      |                                | 1 A   | T <sub>J</sub> = 125 °C               | 0.34   |       |
|                                 |                                | 3 A   |                                       | 0.46   |       |
| Maximum reverse leakage current | ,                              | T <sub>J</sub> = 25 °C  | V <sub>o</sub> = Rated V <sub>o</sub> | 0.5    | mA    |
| See fig. 2                      | I <sub>RM</sub>                | T <sub>J</sub> = 125 °C   |                                       | 20     | IIIA  |
| Threshold voltage               | V <sub>F(TO)</sub>             | $T_J = T_J$ maximum   |                                       | 0.26   | V     |
| Forward slope resistance        | r <sub>t</sub>                 |   |                                       | 64.6   | mΩ    |
| Typical junction capacitance    | C <sub>T</sub>                 | V <sub>R</sub> = 10 V <sub>DC</sub> , T <sub>J</sub> = 25 °C, test signal = 1 MHz |                                       | 134    | pF    |
| Typical series inductance       | L <sub>S</sub>                 | Measured lead to lead 5 mm from package body                                      |                                       | 2.0    | nH    |
| Maximum voltage rate of change  | dV/dt                          | Rated V <sub>R</sub>  |                                       | 10 000 | V/µs  |

#### Note

 $^{(1)}\,$  Pulse width = 300  $\mu s,$  duty cycle = 2 %

| PARAMETER                                       | SYMBOL   | TEST CONDITIONS           | VALUES      | UNITS |
|---|--|---------------------------|-------------|-------|
| Maximum junction and storage temperature range  | T <sub>J</sub> <sup>(1)</sup> , T <sub>Stg</sub> |                           | -40 to +150 | °C    |
| Maximum thermal resistance, junction to ambient | R <sub>thJA</sub>                                | DC operation              | 80          | °C/W  |
| A management and the second select              |  |                           | 0.07        | g     |
| Approximate weight                              |  | 0.002                     | OZ.         |       |
| Marking device                                  |  | Case style SMA (DO-214AC) | 3F          |       |

#### Note

 $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}} \quad \text{thermal runaway condition for a diode on its own heatsink}$ 

#### www.vishay.com

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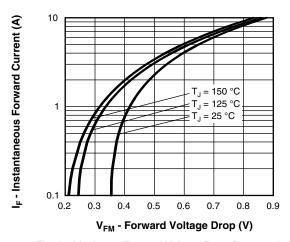


Fig. 1 - Maximum Forward Voltage Drop Characteristics

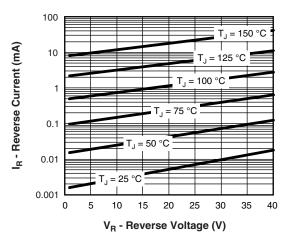


Fig. 2 - Typical Peak Reverse Current vs. Reverse Voltage

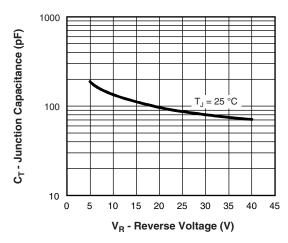
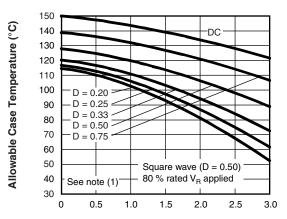


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage



I<sub>F(AV)</sub> - Average Forward Current (A)

Fig. 4 - Maximum Average Forward Current vs. Allowable Lead Temperature

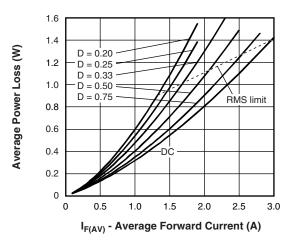


Fig. 5 - Maximum Average Forward Dissipation vs. Average Forward Current

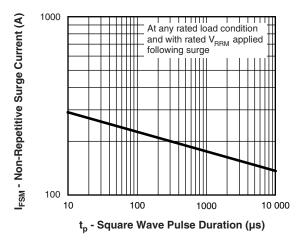


Fig. 6 - Maximum Peak Surge Forward Current vs. Pulse Duration

#### Note

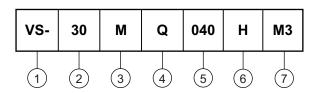
 $^{1)}$  Formula used: T<sub>C</sub> = T<sub>J</sub> - (Pd + Pd<sub>REV</sub>) x R<sub>th,JC</sub>; Pd = Forward power loss = I<sub>F(AV)</sub> x V<sub>FM</sub> at (I<sub>F(AV)</sub>/D) (see fig. 6); Pd<sub>REV</sub> = Inverse power loss = V<sub>R1</sub> x I<sub>R</sub> (1 - D); I<sub>R</sub> at V<sub>R1</sub> = 80 % rated V<sub>R</sub>



## Vishay Semiconductors

### **ORDERING INFORMATION TABLE**

Device code



- Vishay Semiconductors product
- 2 Current rating
- M = SMA
- 4 Q = Schottky "Q" series
- 5 Voltage rating (040 = 40 V)
- 6 H = AEC-Q101 qualified
- 7 Environmental digit:

M3 = Halogen-free, RoHS-compliant and terminations lead (Pb)-free

| ORDERING INFORMATION (Example) |                        |                        |                                    |  |  |
|--------------------------------|------------------------|------------------------|------------------------------------|--|--|
| PREFERRED P/N                  | PREFERRED PACKAGE CODE | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION              |  |  |
| VS-30MQ040HM3/5AT              | 5AT                    | 7500                   | 13" diameter plastic tape and reel |  |  |

| LINKS TO RELATED DOCUMENTS |                          |  |  |
|----------------------------|--------------------------|--|--|
| Dimensions                 | www.vishay.com/doc?95400 |  |  |
| Part marking information   | www.vishay.com/doc?95403 |  |  |
| Packaging information      | www.vishay.com/doc?95404 |  |  |

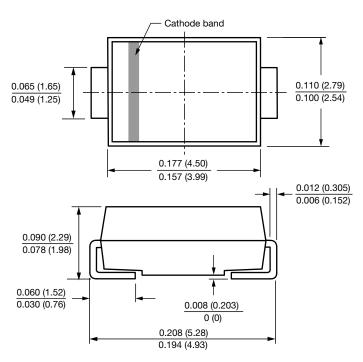


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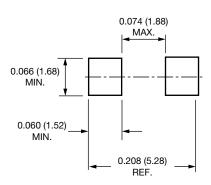
## **SMA**

### **DIMENSIONS** in inches (millimeters)

### **DO-214AC (SMA)**



### **Mounting Pad Layout**





## **Legal Disclaimer Notice**

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